# PE42446

## **Document Category: Product Specification**



High Isolation UltraCMOS® SP4T RF Switch, 10 MHz-8.5 GHz

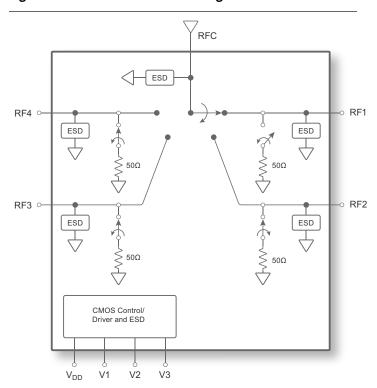
### **Features**

- Operating frequency: Up to 8.5 GHz
- · High isolation: 61 dB @ 4 GHz
- Low insertion loss: 0.75 dB @ 4 GHz
- · High linearity IIP3: 65 dBm @ 3.8GHz
- · Fast switching time: 200 nsec
- -40°C to +125°C operating temperature
- Packaging 24-lead 4×4 mm LGA

## **Applications**

- · DPD feedback loop and VSWR monitoring
- · 5G massive MIMO active antenna systems
- · Analog/hybrid beamforming RF front ends
- · 4G/4.5G TD-LTE macro/micro cell/RRH
- · Test and measurement

Figure 1 • PE42446 Functional Diagram



## **Product Description**

The PE42446 is a HaRP™ technology-enhanced SP4T RF switch designed for use in 4G/5G wireless infrastructure and other high performance RF applications. It is comprised of four symmetric RF ports with very high isolation up to 8.5 GHz. The PE42446 is manufactured on pSemi's UltraCMOS® process, a patented variation of silicon-on-insulator (SOI) technology. pSemi's HaRP technology enhancements deliver high isolation, linearity and excellent harmonics performance.

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Product Specification DOC-109482-9 – (08/2024)



# **Revision History**

### Table 1 ■ Revision History

Document Revision	Date	Change Description
DOC-109482-5	November 2023	Upper frequency range
DOC-109482-6	December 2023	Features section Table 2, Absolute Maximum Ratings Table 3, Recommended Operating Conditions Table 4, Electrical Specifications Figure 3, Package Mechanical Drawing
DOC-109482-7	February 2024	Figures 2 through 17, Typical Performance Data Table note in Tables 5 and 6 Figure 21, Tape and Reel Specification
DOC-109482-8	July 2024	Pin information
DOC-109482-9	August 2024	Table 5, SP4T Control Logic Table 6, Truth Table of 2-pin Control Only



# **Absolute Maximum Ratings**

Exceeding absolute maximum ratings listed in **Table 2** may cause permanent damage. Operation should be restricted to the limits in **Table 4**. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

### **ESD Precautions**

When handling this UltraCMOS device, observe the same precautions as with any other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in **Table 2**.

### Latch-up Immunity

Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.

Table 2 ■ Absolute Maximum Ratings for PE42446

Description	Min	Тур	Max	Unit
Power supply voltage	2.3		5.5	V
Digital input voltage (V1, V2, V3)	-0.3		3.6	V
Storage temperature range	-60		150	°C
Maximum junction temperature range			150	°C
RF input RMS power, RFX to RFC, hot switching, LTE PAR 9 dB, freq = 3.8 GHz @105°C			29	dBm
RF input RMS power, RFX to RFC, hot switching, LTE PAR 9 dB, freq = 3.8 GHz @125°C			26	dBm
RF input RMS power terminated port, hot switching, LTE PAR 9 dB, freq = 3.8 GHz @105°C			29	dBm
RF input RMS power terminated port, hot switching, LTE PAR 9 dB, freq = 3.8 GHz @125°C			26	dBm
ESD voltage HBM1, all pins <sup>(1)</sup>			2000	V
ESD voltage CDM2, all pins <sup>(2)</sup>			1000	V

#### Notes

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<sup>1)</sup> Human body model (MIL-STD 883 Method 3015).

<sup>2)</sup> Charged device model (JEDEC JESD22-C101).



# **Recommended Operating Conditions**

**Table 3** lists the recommended operating conditions for the PE42446. Devices should not be operated outside the operating conditions listed below.

Table 3 ■ Recommended Operating Conditions for PE42446

Parameter	Min	Тур	Max	Unit
V <sub>DD</sub> supply voltage	2.3	3.3	5.5	V
Power supply current V <sub>DD</sub> = 3.3V		95	250	μA
Control voltage high	1.07		3.6	V
Control voltage low	-0.3		0.68	V
Control current V1 high		2		μA
Control current V1 low		2		μA
Control current V2 high		2		μA
Control current V2 low		2		μA
Control current V3 high		2		μA
Control current V3 low		2		μA
Operating temperature range	-40		125	°C
Frequency range	10		8500	MHz
RF input power, CW (P <sub>MAX,CW</sub> +105°C)			34	dBm
RF input power, CW (P <sub>MAX,CW</sub> +125°C)			32	dBm
RF input power into terminated ports, CW (P <sub>MAX,CW</sub> +105°C)			25	dBm
RF input power into terminated ports, CW (P <sub>MAX,CW</sub> +125°C)			21	dBm



# **Electrical Specifications**

**Table 4** provides the PE42446 key electrical specifications @ +25°C (ZS = ZL =  $50\Omega$ ), unless otherwise specified.

Table 4 ■ PE42446 Electrical Specifications

Parameter	Condition	Min	Тур	Max	Unit
Frequency Range		10		8500	MHz
	10 to 900 MHz		0.60	0.72	dB
	900 to 2100 MHz		0.66	0.78	dB
	2100 to 2700 MHz		0.70	0.88	dB
Insertion Loss, RFX to RFC	2700 to 4000 MHz		0.75	0.99	dB
	4000 to 6000 MHz		0.82	1.12	dB
	6000 to 8000 MHz		1.05	1.47	dB
	8000 to 8500 MHz		1.27	1.50	dB
	10 to 900 MHz		72		dB
	900 to 2100 MHz		66		dB
	2100 to 2700 MHz		65		dB
Isolation, RFX to RFC	2700 to 4000 MHz		61		dB
	4000 to 6000 MHz		55		dB
	6000 to 8000 MHz		47		dB
	8000 to 8500 MHz		45		dB
	10 to 900 MHz		59		dB
	900 to 2100 MHz		53		dB
	2100 to 2700 MHz		50		dB
Isolation, RFX to RFX	2700 to 4000 MHz		47		dB
	4000 to 6000 MHz		43		dB
	6000 to 8000 MHz		39		dB
	8000 to 8500 MHz		38		dB
	10 to 900 MHz		24		dB
	900 to 2100 MHz		20		dB
	2100 to 2700 MHz		19		dB
Return Loss, RF1/2/3/4 On State	2700 to 4000 MHz		19		dB
	4000 to 6000 MHz		17		dB
	6000 to 8000 MHz		12		dB
	8000 to 8500 MHz		10		dB

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## PE42446 SP4T RF Switch



### Table 4 ■ PE42446 Electrical Specifications (Cont.)

Parameter	Condition		Тур	Max	Unit
	10 to 900 MHz		25		dB
	900 to 2100 MHz		21		dB
	2100 to 2700 MHz		21		dB
Return Loss, RF1/2/3/4 Off State	2700 to 4000 MHz		21		dB
	4000 to 6000 MHz		18		dB
	6000 to 8000 MHz		17		dB
	8000 to 8500 MHz		14		dB
Input 0.1dB Compression	3800 MHz		36.8		dBm
Input IP3, RFX to RFC	3800 MHz		65.5		dBm
Input IP2, RFX to RFC	3800 MHz		110		dBm
Switching time	50% CTRL to 90% or 10% RF		200		ns



# **SP4T Control Logic**

Table 5 provides the control logic truth table for the PE42446.

Table 5 • Truth Table for PE42446

ON Port	V3	V2	V1
RF4 on <sup>(*)</sup>	0	0	0
RF1 on	0	0	1
RF2 on	0	1	0
RF3 on	0	1	1
RF4 on	1	0	0
All off	1	0	1
All off	1	1	0
All off	1	1	1

Note: \* Pin 19 (V3) must be grounded for 2-pin control. 2-pin control can be used if All off mode is not required.

# Truth Table of 2-pin Control Only

Table 6 provides the truth table for 2-pin control of the PE42446.

Table 6 ■ 2-pin Control Truth Table for PE42446

Mode	V2	V1
RF4 on <sup>(*)</sup>	0	0
RF1 on	0	1
RF2 on	1	0
RF3 on	1	1

Note: \* Pin 19 (V3) must be grounded for 2-pin control. 2-pin control can be used if All off mode is not required.

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# **Typical Performance Data**

**Figure 2–Figure 17** show the typical performance data at +25 °C TCASE, VDD = 5V (ZS = ZL =  $50\Omega$ ), unless otherwise specified.

Figure 2 • Insertion Loss vs. Switch Path

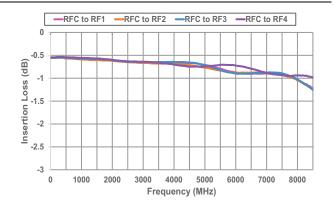


Figure 3 • Insertion Loss vs. Temperature

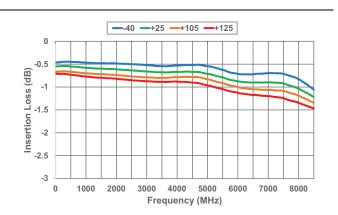


Figure 4 • Insertion Loss vs. Voltage

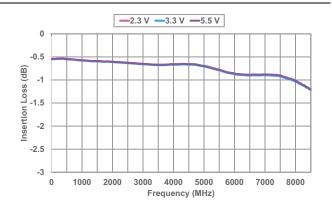


Figure 5 • Isolation (RFC-RFX) vs. Switch Path

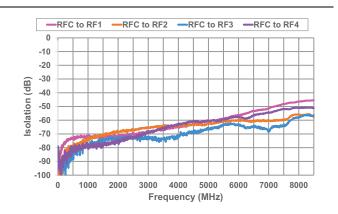


Figure 6 • Isolation (RFC-RFX) vs. Temperature

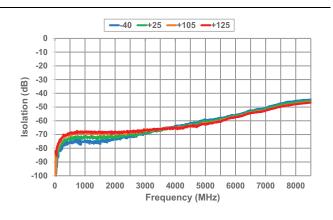


Figure 7 • Isolation (RFC-RFX) vs. Voltage

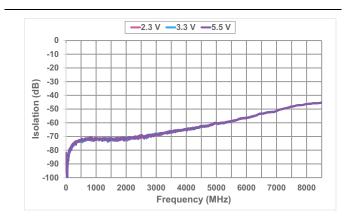




Figure 8 • Isolation (RFX-RFX) vs. Temperature

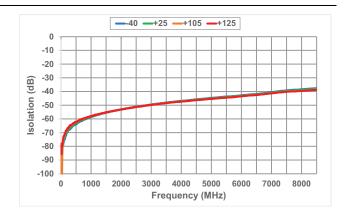


Figure 10 • RFX Return Loss vs. Switch Path

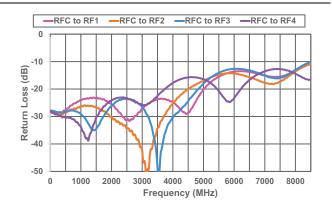


Figure 12 • RFX Return Loss vs. Voltage

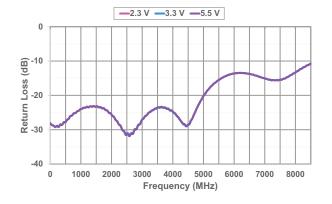


Figure 9 • Isolation (RFX-RFX) vs. Voltage

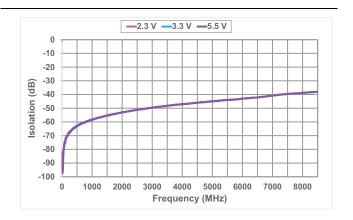


Figure 11 ■ RFX Return Loss vs. Temperature

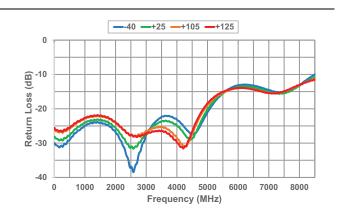
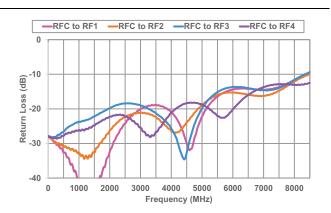


Figure 13 • RFC Return Loss vs. Switch Path



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Figure 14 • RFC Return Loss vs. Temperature

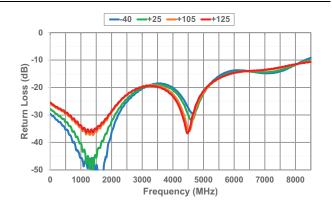


Figure 16 • RFX Terminated, Return Loss

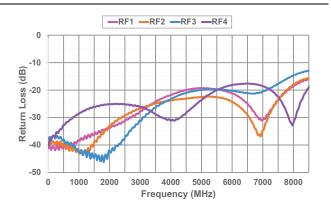


Figure 15 • RFC Return Loss vs. Voltage

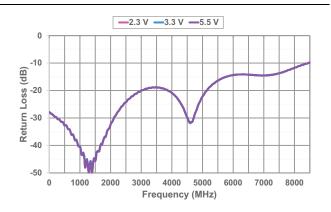
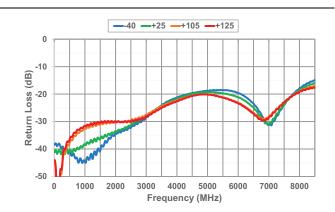


Figure 17 • RFX Terminated, Return Loss vs. Temperature





### Pin Information

This section provides pinout information for the PE42446. **Figure 18** shows the pin map of this device for the available package. **Table 7** provides a description for each pin.

Figure 18 • Pin Configuration (Top View)

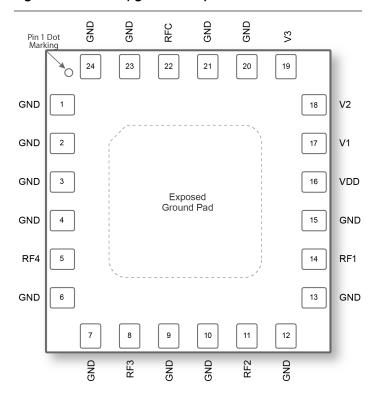


Table 7 ■ Pin Descriptions for PE42446

Pin No.	Pin Name	Description	
1,2,3,4,6,7, 9,10,12,13, 15,20,21, 23,24	GND	Ground	
5	RF4	RF port 4	
8	RF3	RF port 3	
11	RF2	RF port 2	
14	RF1	RF port 1	
16	VDD	Supply voltage	
17	V1	Digital control logic input 1	
18	V2	Digital control logic input 2	
19	V3	Digital control logic input 3	
22	RFC	RF common	
25	GND	Exposed pad: Ground for proper operation.	



# **Packaging Information**

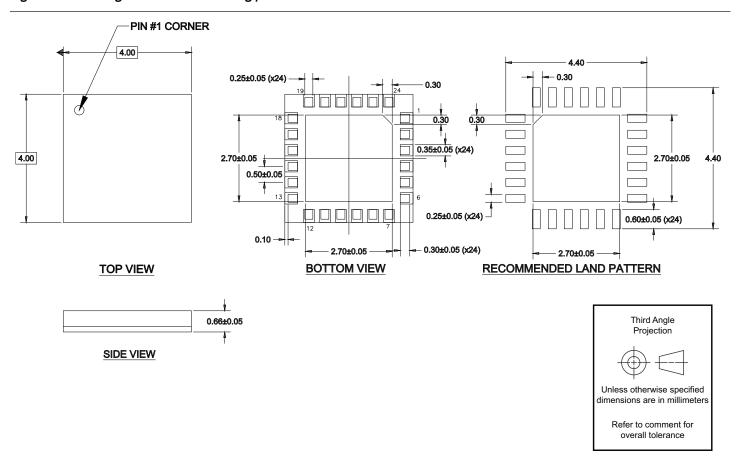
This section provides packaging data including the moisture sensitivity level, package drawing, package marking and tape-and-reel information.

### **Moisture Sensitivity Level**

The moisture sensitivity level rating for the PE42446 in the 24-lead 4×4 mm LGA package is MSL 3.

### **Package Drawing**

Figure 19 • Package Mechanical Drawing for 24-lead 4×4 mm LGA





### **Top-Marking Specification**

Figure 20 ■ Package Marking Specifications for PE42446 [TBD]



= Pin 1 indicator

42446 = Product part number

YY = Last two digits of assembly year (2022 = 22)

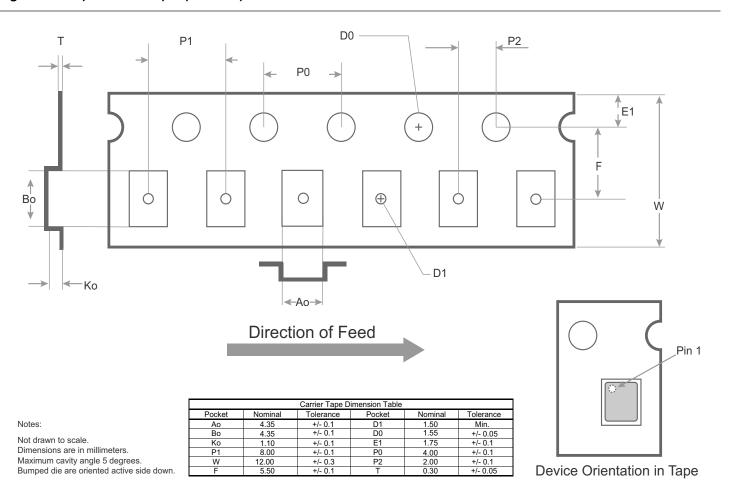
WW = Work week of assembly lot start date (01, ..., 52)

ZZZZZZ = Assembly lot code (max six characters)

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### Tape and Reel Specification

Figure 21 • Tape and Reel Specifications for 24-lead 4×4 mm LGA





## **Ordering Information**

Table 8 lists the available ordering codes for the PE42446 as well as available shipping methods.

#### Table 8 • Order Codes for PE42446

Order Codes	Description	Packaging	Shipping Method	
PE42446A-Z	PE42446 SP4T RF switch	Green 24-lead 4×4 mm LGA	3000 units/T&R	
EK42446-01	PE42446 Evaluation kit	Evaluation kit	1/box	

### **Document Categories**

### **Advance Information**

The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

#### Preliminary Specification

The datasheet contains preliminary data. Additional data may be added at a later date. pSemi reserves the right to change specifications at any time without notice in order to supply the best possible product.

#### Product Specification

The datasheet contains final data. In the event pSemi decides to change the specifications, pSemi will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

#### **Product Brief**

This document contains a shortened version of the datasheet. For the full datasheet, contact sales@psemi.com.

#### Sales Contact

For additional information, contact Sales at sales@psemi.com.

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